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EuMC23 Millimeter-wave Transition Structures and Packaging Techniques

Chair: Mehmet Kaynak¹
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²XLIM Research Institute, University of Limoges,
Limoges, France

EuMC24 Planar Filters II

Chair: Roberto Gómez-García¹
Co-Chair: Dimitra Psychogiou²
¹University of Alcalá, ²University of Colorado
Boulder

13:50 - 14:10

EuMC23-1 D-band Silica-Based Package Substrate with EBG Structure for Flip- Chip Modules

Masaharu Ito¹, Tsunehisa Marumoto¹
¹NEC Corporation

EuMC24-1 Compact Square/Triangle Mixed-Shape Quarter- Mode Substrate Integrated Waveguide Bandpass Filter with Wide Stopband

Phirun Kim¹, Wang Qi¹, Phanam Pech¹, Junhyung
Jeong¹, Yongchae Jeong¹
¹Chonbuk National University

14:10 - 14:30

EuMC23-2 F-band Low-loss Tapered Slot Transition for Millimeter-wave System Packaging

Ahmed Hassona¹, Zhongxia Simon He¹, Vessen
Vassilev¹, Herbert Zirath¹
¹Chalmers University of Technology

EuMC24-2 Multilayered Wideband Balun Bandpass Filters Designed with Input- Reflectionless Response

Li Yang¹, Roberto Gómez-García¹, José-María
Muñoz-Ferreras¹, Wenjie Feng²
¹University of Alcalá, ²Nanjing University of Science
and Technology

14:30 - 14:50

EuMC23-3 A Compact 28 GHz RF Front-end Module using IPDs and Wafer-level Metal Fan-out Packaging

Jongmin Yook¹
¹KETI (Korea Electronics Technology Institute)

EuMC24-3 Topology and Rigorous Design Method for Reflectionless Bandstop Filter

Jongheun Lee¹, Boyoung Lee¹, Seunggoo Nam¹,
Juseop Lee¹
¹Korea University

14:50 - 15:10

EuMC23-4 Broadband Stacked-Patch Transition from Microstrip Line to Circular Dielectric Waveguide for Dual- Polarized Applications at W-Band Frequencies

Andre Meyer¹, Martin Schneider¹, Simon Karau¹
¹Universität Bremen

EuMC24-4 Magnet-less Non- Reciprocal Bandpass Filters With Tunable Center Frequency

Dakotah Simpson¹, Dimitra Psychogiou¹
¹University of Colorado at Boulder

15:10 - 15:30

EuMC23-5 A Novel Miniaturized High Performance BGA RF Transition for Ka Band Applications

Firat Altuntas¹
¹Aselsan Inc.

EuMC24-5 Design of Wideband Bandpass Filters Using Parallel-Coupled Asymmetric Three Line Structures with Adjustment Elements

Elif Güntürkün Şahin¹, Ali Kursad Gorur², Ceyhan
Karpuz², Adnan Gorur¹
¹Nigde Omer Halisdemir University, ²Neveşehir Haci
Bektas Veli University, ³Pamukkale University

Compact Square/Triangle Mixed-Shape Quarter-Mode Substrate Integrated Waveguide Bandpass Filter with Wide Stopband

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Abstract—In this paper, a new square/triangle mixed-shape quarter-mode substrate integrated waveguide (SIW) bandpass filter (BPF) is presented. Two transmission poles in the passband and two transmission zeros (TZs) in the stopband can be obtained by using a mixed quarter-mode cavity sharp. For an experimental validation, two-stage with square/triangle mixed-shape quarter-mode SIW BPF is designed at the center frequency (f_0) of 8 GHz. From measurements, the insertion loss (S_{21}) and return loss (S_{11}) of 1.1 dB and 15.1 dB are obtained at f_0 , respectively. The passband insertion loss is better than 1.3 dB in the bandwidth of 0.87 GHz (7.55 ~ 8.42 GHz). The return losses better than 15.1 dB for the same bandwidth is measured. The two TZs in stopband make the attenuation characteristics better than 39.6 dB and 33 dB at 11.44 GHz and 15.67 GHz, respectively. And the proposed SIW BPF is compact due to mixed-shape quarter-mode shape.

Keywords—bandpass filter, quarter-mode resonator, substrate integrated waveguide.

I. INTRODUCTION

Bandpass filters (BPFs) with compact-size, low-cost, and high performances are researched and developed dramatically in recent years. Substrate integrated waveguide (SIW) BPF is one of the planar circuits that can provide high Q-factor, low-loss, working on low/high frequency, high power-handling capability, and easy integration with other planar circuits [1].

The SIW circuit has been developed for various purposes using full-mode, half-mode, and quarter-mode cavities to design BPF and antennas [2]-[12]. In [2], the SIW BPF has been designed at millimeter wave using full-mode cavities with magnetic and electric couplings. The SIW impedance transformer is presented in [3] using a full-mode cavity. The impedance transforming ratio can be controlled by changing the input/output couplings. In [4], the oversized SIW cavities are used to design BPF with multiple transmission zeros (TZs) without cross-coupling structure. Moreover, the stopband attenuation is also improved. Similarly, the dual-mode cavities and air-filled SIW BPF with multiple TZs are presented in [5]. The resonance frequency of the cavity can be controlled by removing dielectric substrate partially of the SIW cavity. In [6], dual-mode circular SIW BPF designed with different size

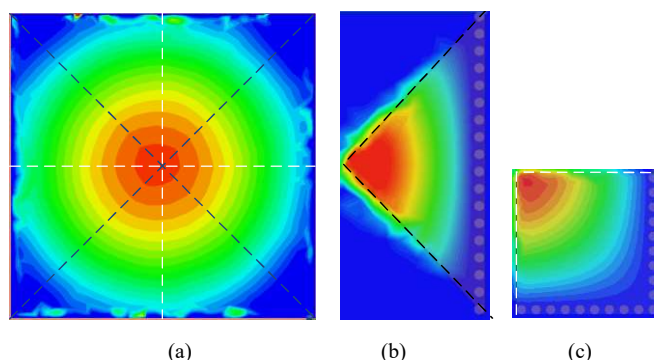


Fig. 1. SIW resonators: (a) full-mode cavity, (b) triangle quarter-mode cavity, and (c) square quarter-mode cavity.

cavities and two extra via-hole inside the cavities produces transmission poles (TPs) and controllable TZs without cross-coupled resonators. Similarly, the circular cavity with cross-coupled resonators is designed to produce TZs near to the passband with high selectively performance [7]. Since the full-mode cavity has a large circuit size, the quarter-mode resonator is analyzed and can reduce a circuit size up to 75% compared to a full-mode cavity [8]. With this benefit, the quarter-mode SIW cavities are used to design antennas [9] and sub-array antennas [10]. On the other hand, the quarter-mode cavity SIW is also used to design BPF with a very compact circuit size. In [11], one-quarter of the square shape SIW cavity is analyzed and used to design SIW BPF with different coupling mechanisms of the cavity. Moreover, single-band and dual-band SIW BPFs with one-third-mode of triangle cavity is proposed [12]. The dual-band BPF can be obtained by making two extra inductive windows at the edge of the resonators.

In this paper, a square/triangle mixed-shape quarter-mode SIW BPF is proposed. The quarter-mode square cavity is coupled to the quarter-mode triangle shape cavity by using a magnetic coupling that controlled with a sharing iris window. The obtained TZs can improve stopband attenuation characteristic by using square/triangle mixed-shape quarter-mode cavities. Moreover, the circuit size of the proposed filter is compact.



Fig. 2. Coupling structure of coupled resonators bandpass filter.

II. QUARTER-MODE SIW RESONATORS

Fig. 1 shows the SIW resonators with full-mode, quarter-mode with triangle, and quarter-mode with square structure, respectively. The quarter-modes of triangle and square structures have been analyzed and used in filter and antenna designs [8], [10]-[13]. The quarter-mode triangle cavity has one electric sidewall and two magnetic sidewalls. However, the quarter-mode square cavity has two electric sidewalls and two magnetic sidewalls. Both cavities have the same resonance frequency with a size only one-quarter of the full-mode resonator structure as shown in Fig. 1. The general SIW BPFs are designed using the magnetic coupling with a sharing via-hole window. For the proposed filter, the quarter-modes with square /triangle structure cavities are designed together. By mixing both resonators, the TZs in the stopband can be obtained and provided a wide stopband characteristic.

For the proposed filter, the general coupling structure of the coupled resonators is shown Fig. 2. r_1 to r_n are the resonators. S and L stand for source and load terminations ($Z_S = Z_L = Z_0$). Q_{eS} and Q_{eL} are the external quality factor at the source and load, respectively. Moreover, $K_{i,i+1}$ is a coupling coefficient between i -th and $i+1$ -th resonators. The $Q_{eS,eL}$ and $K_{i,i+1}$ can be calculated from (1) [1].

$$Q_{eS} = Q_{eL} = \frac{g_{0,n}g_{1,n+1}}{\text{FBW}} \quad (1a)$$

$$K_{i,i+1} = \frac{\text{FBW}}{\sqrt{g_i g_{i+1}}} \quad (1b)$$

where $g_0, g_1, \dots,$ and g_{n+1} are the low-pass prototype element values. FBW is the fractional bandwidth of the passband.

The electromagnetic (EM) simulation is used to extract the Q_{eS}, Q_{eL} , and $K_{i,i+1}$ by the following equations (2) and (3)-(4), respectively.

$$Q_{eS,eL} = \frac{f_0}{\Delta f_{\pm 3\text{dB}}} \quad (2)$$

where $\Delta f_{\pm 3\text{dB}}$ is the 3-dB bandwidth of the center frequency (f_0). Moreover, $K_{i,i+1}$ can be calculated from (3) for the tuned coupled resonator synchronously.

$$K_{i,i+1} = \frac{f_{p2}^2 - f_{p1}^2}{f_{p2}^2 + f_{p1}^2} \quad (3)$$

where i is a value in the range of 2 to $n-1$. Similarly, the coupling coefficient between two resonators (K_{12} and $K_{n,n+1}$) can be calculated from (4) for the asynchronous case.

$$K_{1,2} = K_{n-1,n} = \pm \frac{1}{2} \left(\frac{f_{R_1}}{f_{R_2}} + \frac{f_{R_2}}{f_{R_1}} \right) \sqrt{\left(\frac{f_{p_2}^2 - f_{p_1}^2}{f_{p_2}^2 + f_{p_1}^2} \right)^2 - \left(\frac{f_{R_2}^2 - f_{R_1}^2}{f_{R_2}^2 + f_{R_1}^2} \right)^2} \quad (4)$$

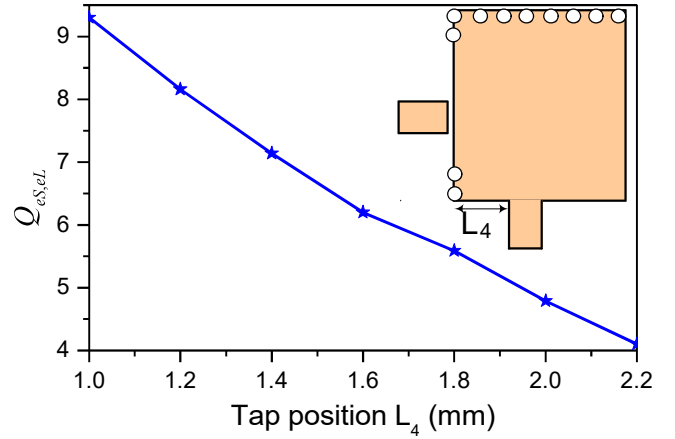


Fig. 3. Extracted quality factor according to tap position of square cavity.

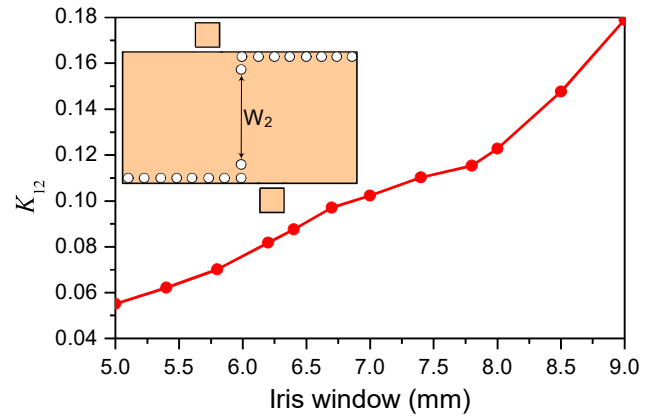


Fig. 4. Extracted coupling coefficient K_{12} according to iris window width of the square/square cavities SIW BPF.

where f_{R_j} ($j = 1, 2$) is a self-resonance frequency and f_{p_j} is the two split resonant frequencies.

To verify the proposed filter, two SIW BPFs have been designed to operate at f_0 of 8 GHz with passband ripple of 0.043 dB, two-stage resonators, and FBW of 9%. One filter is designed with quarter-mode square/square cavities and other filter is designed with mix square/triangle cavities. The filter is designed on RT/Duriod 5880 substrate with dielectric constant (ϵ_r) of 2.2 and thickness (h) of 0.52 mm. From [1], $g_0 = 1, g_1 = 0.6648, g_2 = 0.5445,$ and $g_3 = 1.221$ are extracted for 0.043 dB of the passband ripple. According to (1), the $Q_{eS} = Q_{eL} = 7.387$ and $K_{12} = 0.1496$ are calculated.

Using EM simulation, the $Q_{eS,eL}$ according to the tap position (L_4) of the square cavity can be extracted and calculated using (2), as shown in Fig. 3. The $Q_{eS,eL}$ is controlled by tapping from the short-circuit of via-hole [1]. It is note that $Q_{eS,eL}$ is decreased as the tap position from the via-hole increases. Similarly, the coupling coefficient (K_{12}) of the square/square cavities is extracted from the EM simulation using (3)-(4). Fig. 4 shows the K_{12} according to the width of a sharing iris window (W_2). As can be seem, the K_{12} is increased as the width of iris window increases.

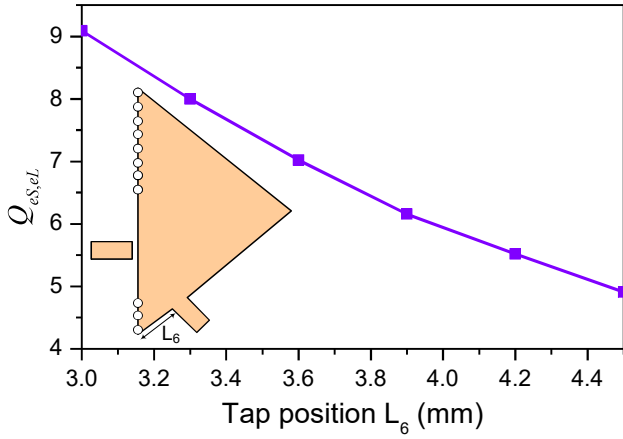


Fig. 5. Extracted quality factor according to tap position of triangle cavity.

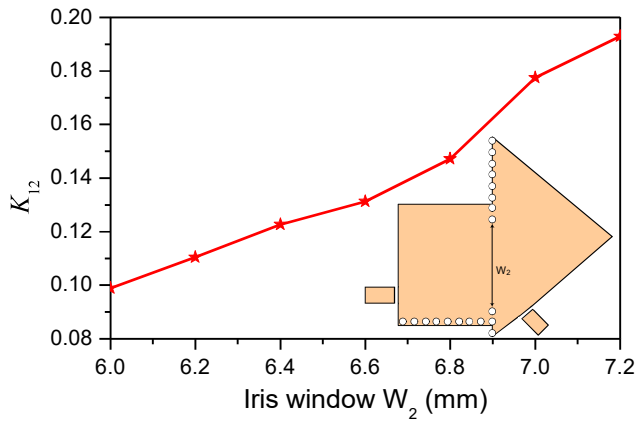


Fig. 6. Extracted coupling coefficient K_{12} according to iris window width of the square/triangle cavities SIW BPF.

For the mixed of square/triangle cavities, the designed processes are the same. The $Q_{es,el}$ of the square/triangle cavities can be extracted from the EM simulation by controlling a tap position as shown in Fig. 5. As can be seen, the $Q_{es,el}$ is decreased as the tap position from the via-hole increases. Moreover, the quarter-mode square cavity is coupled to the bottom of quarter-mode triangle cavity and controlled by a sharing iris window width (W_2) as can be seen in Fig. 6. As can be seen, the K_{12} is increased as the W_2 increases.

Fig. 7 shows layout of two-stage quarter-mode with square/square and square/triangle cavities SIW BPFs. Two SIW BPFs are designed with the same specifications as mentioned early. According to calculation $Q_{es} = Q_{el} = 7.387$ and $K_{12} = 0.1496$ are required for the specifications. From Figs. 3, 4, 5, and 6, the tap position and iris window width are extracted. The final physical lengths are shown in Figs. 7(a) and 7(b) for square/square and square/triangle cavities SIW BPFs, respectively. Similarly, Fig. 8 shows the S -parameters comparison of both filters. From the simulation, the quarter-mode SIW BPF with square/square cavities produces a

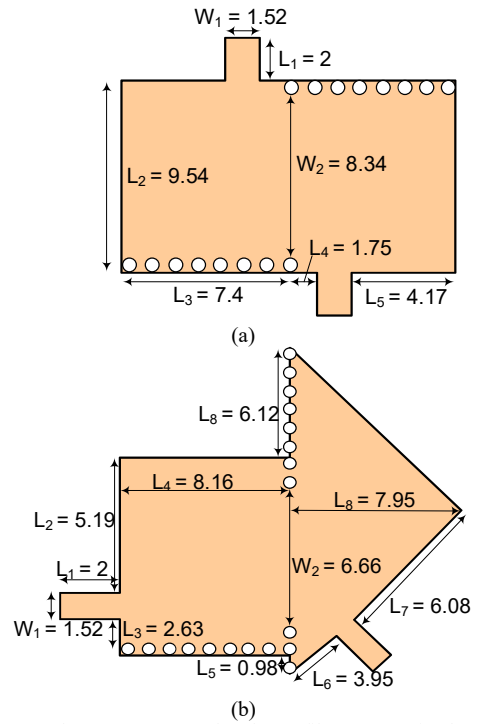


Fig. 7. Layout of two-stage SIW bandpass filters: (a) mixed square/square cavities and (b) square/triangle cavities. (unit: mm)

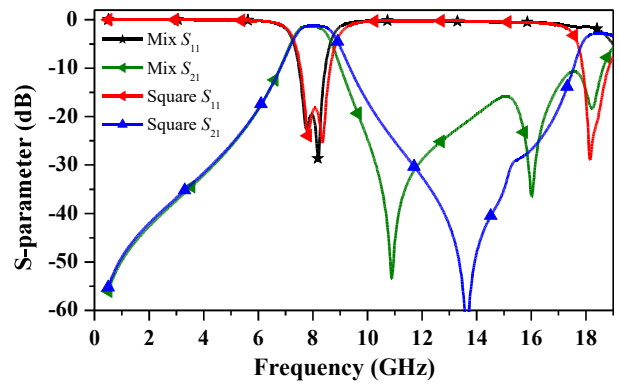


Fig. 8. EM simulation of two-stage quarter-mode SIW BPF with square/square and square/triangle cavities.

spurious frequency at 18 GHz ($2.25f_0$) with a TZ at 13.6 GHz. Moreover, two TPs in the passband are obtained with FBW of 8.5% (8.39-7.71 GHz). However, the quarter-mode SIW BPF with square/triangle cavities also produce two TPs in the passband. The first and second TZs are produced by the triangle and square cavities, respectively. The second TZ is located at the second passband ($2f_0$) which is useful in RF system performance. Moreover, the spurious frequency of proposed filter is located higher than the square cavity filter. Thus, the proposed quarter-mode SIW BPF with square/triangle cavities provides extra TZs, higher selectivity and higher spurious frequency with a compact circuit size.

III. SIMULATION AND MEASUREMENT

To validate the proposed filter, two-stage quarter-mode SIW BPF with square/triangle cavities resonator is designed and fabricated.



Fig. 9. Photograph of fabricated quarter-mode SIW BPF with square/triangle cavities.

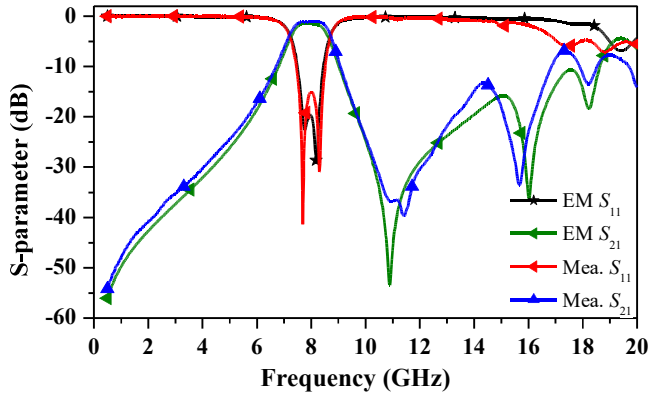


Fig. 10. S-parameters of proposed quarter-mode SIW BPF with square/triangle cavities.

The filter is designed with the same specifications and substrate as mentioned in the early section. The layout of proposed filter is shown in Fig. 7(b).

Fig. 9 shows the photograph of the fabricated two-stage quarter-mode SIW BPF. The overall size of the proposed circuit is $16.76 \text{ mm} \times 18.11 \text{ mm}$. The simulated and measured S-parameters of the proposed filter are shown in Fig. 10. The measured input return loss is better than 15.1 dB at the f_0 . Moreover, the return loss better than 15.1 dB is measured within the operating band of 7.55-8.42 GHz (FBW = 10.89%). The measured insertion loss (S_{21}) at the f_0 is 1.1 dB, showing a good agreement with the simulation result. Within the same passband, the measured insertion loss is better than 1.3 dB. The fabricated filter provides a wide stopband attenuation with two TZs. The TZs at 11.44 GHz ($1.43f_0$) and 15.67 GHz ($1.95f_0$) are measured and attenuated better than 39.6 dB and 33 dB, respectively. The attenuation at the lower stopband is measured better than 15 dB from dc to 6.25 GHz. Similarly, the attenuation at the higher stopband is measured better than 13 dB from 9.26 GHz to 16.63 GHz. Moreover, the spurious frequency of proposed filter is located higher than the 18 GHz ($2.25f_0$).

IV. CONCLUSION

In this paper, a quarter-mode SIW BPF with square/triangle cavities resonators is presented. Both the simulation and measurement results are provided to validate the proposed

circuits. The circuit size of proposed filter is compact about 75% smaller than full-mode resonators. The proposed filter of square/triangle mixed-shape quarter-mode cavities can produce two TZs in the stopband. Moreover, the first spurious frequency is occurred far away from the fundamental. The proposed filter is simple structure to design in microstrip.

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